# **Automated MOSFET Multi-Objective Optimisation using LTspice and Python**

## Project Overview

This document describes a powerful automation script designed for multi-objective optimisation of MOSFET parameters (Channel Length and Width ) within an LTspice simulation environment.

The core objective is to find the optimal and values that maximise the transient peak current () while minimising the transistor area (). This is solved using a weighted cost function minimised by a global optimisation algorithm.

The project demonstrates a robust, automated workflow for integrating industry-standard SPICE simulation tools with advanced Python scientific libraries for parameter optimisation in analog/mixed-signal design.

## Technical Approach & Features

The optimisation loop uses Python to control the simulation, eliminating the need for manual parameter sweeping in LTspice.

### **Key Components**

- 1. LTspice Integration: The script programmatically generates a new Netlist file (optimization transient.net) for each optimisation iteration, inserting the new and parameters.
- 2. Batch Simulation: LTspice is executed in batch mode (-b flag) via subprocess to perform the transient simulation and generate the binary .raw file.
- 3. Data Extraction: The PyLTSpice library is used to read the raw simulation data, and NumPy extracts the critical performance metric: the maximum transient load current,
- 4. Multi-Objective Cost Function: The optimiser minimises a cost function that balances performance () and cost (Area): \$ \text{Cost} = (-I {on}) + (\text{AREA PENALTY FACTOR} \cdot L \cdot W) \$\$ (Where is maximised by minimising)
- 5. Differential Evolution: The SciPy differential\\_evolution algorithm is employed for robust, global optimisation across the design search space.
- 6. **Visualization:** Generates high-quality plots showing the convergence of the cost function, the evolution of and over iterations, and a 3D visualization of the search path.

#### **Design Under Test (DUT)**

The Netlist template defines a basic NMOS switch circuit with a parasitic inductor () on the supply line to introduce dynamic effects, making the transient an important metric.

```
Vdd Vdd_clean 0 DC 5
Lp Vdd_clean Vdd_supply 1n
Vg G 0 PULSE(0 5 0 1n 1n 1u 2u)
Rload Vdd_supply D 1k
M1 D G 0 0 NMOS L={L_val}u W={W_val}u
.model NMOS NMOS (VTO=0.7 KP=120u)
.tran 0.1u 5u
```

## Getting Started

### **Prerequisites**

- 1. **LTspice:** Must be installed on your machine.
- 2. **Python 3.x:** Installed environment.

#### **Installation**

- 1. Clone this repository:
- 2. git clone
   [https://github.com/YourUsername/RepoName.git] (https://github.com/You
   rUsername/RepoName.git)
- 3. cd RepoName
- 4. Install the required Python packages:
- 5. pip install numpy scipy matplotlib PyLTspice

### Configuration

You must update the path to your LTspice executable in the Python script:

```
In optimize_mosfet_v5.py:
# IMPORTANT: Update this path to match your local LTspice installation
executable path.
LTSPICE_PATH =
r"C:\Users\Kris\AppData\Local\Programs\ADI\LTspice\LTspice.exe"
```

### **Running the Optimisation**

Execute the main script:

```
python optimize mosfet v5.py
```

The script will print the real-time progress of the differential evolution algorithm to the console, showing the , , , and Cost for each simulation run.

Upon completion, the final optimal parameters and performance metrics will be displayed, and the file optimization results.png will be generated with the convergence plots.